



The New Stone Age

Tiffany Kaspar, Materials Scientist
Pacific Northwest National Laboratory



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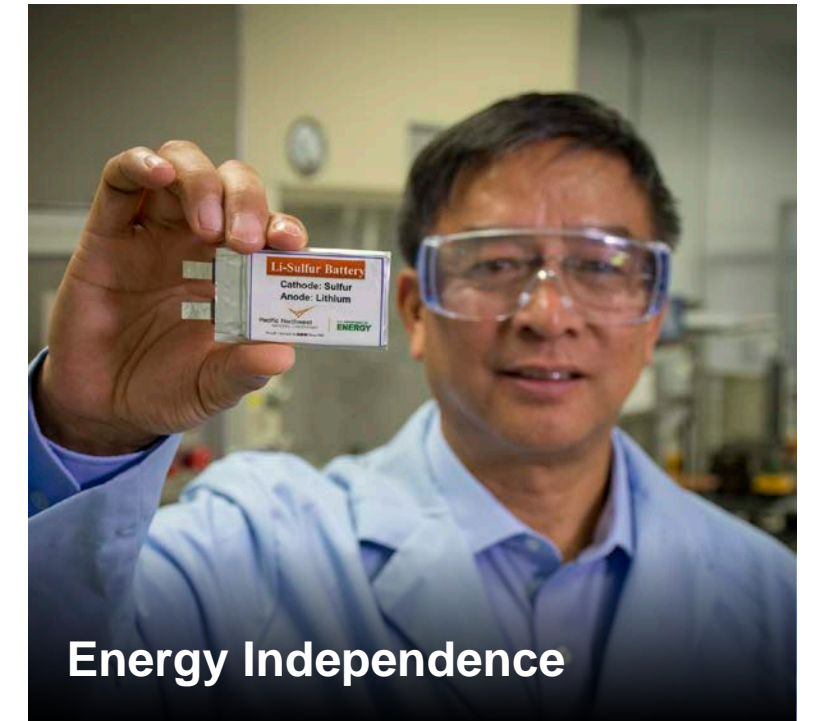
We value your feedback!

<https://www.surveymonkey.com/r/PNNL090820>

1 of 17 U.S. DOE Labs



PNNL is
Focused on
DOE's
MISSIONS
and
Addressing Critical
NATIONAL
NEEDS





PNNL is an **ECONOMIC ENGINE**



4,722
Employees



265
Inventions



\$1.46B
Total Economic Output



\$1.01B
Annual Spending



88
Patents



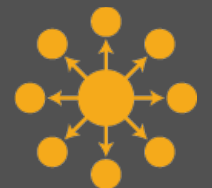
7,180
Jobs Generated
in Washington



\$465M
Total Payroll



34
Licenses



193
Companies
with PNNL Roots

50+ Years

Developing Goodwill



Decades **\$28.5M**

FY19 **\$0.52M**

Philanthropic
Investments

347,000

30,000

Team Battelle
Volunteer Hours

>120

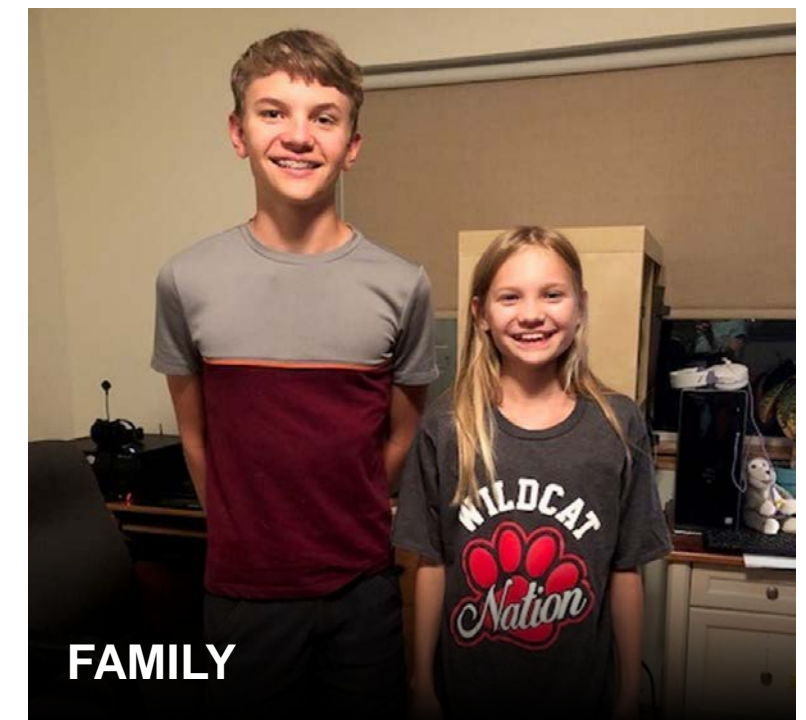
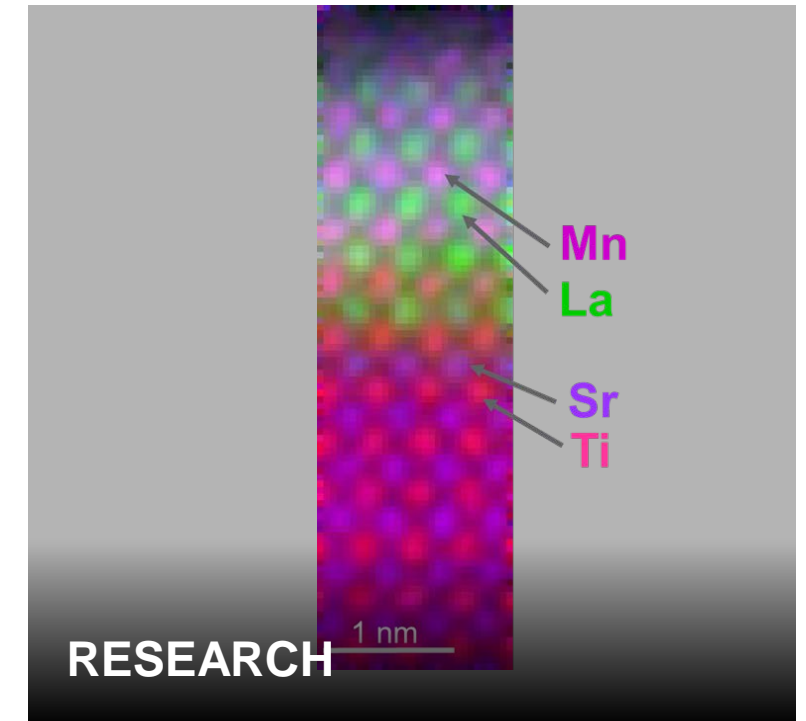
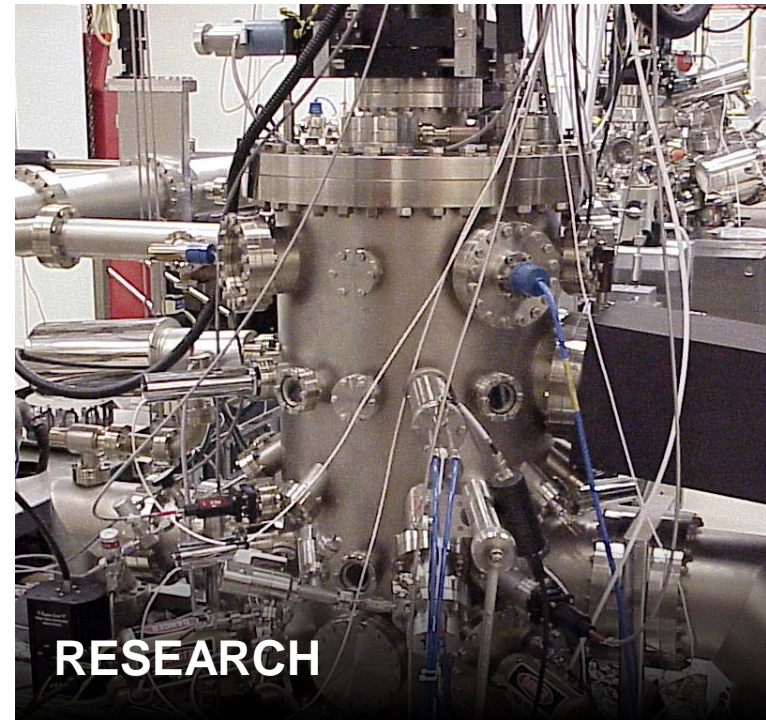
56

Community
Organizations

A little about me...

Tiffany Kaspar

- B.S. Chemical Engineering, CU-Boulder, 1998
- Ph.D. Chemical Engineering, UW, 2004
- At PNNL since 2000



The New Stone Age

September 9, 2020

Tiffany Kaspar

Senior Research Scientist

Atomically Precise Materials Group

Materials Sciences Division

Hypothesis:

Oxides (in the form of rocks) began human technological development

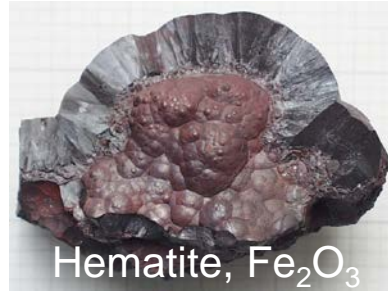
And

Oxides (in the form of advanced materials precisely synthesized at the atomic scale) will soon...

SAVE THE WORLD!!

What are oxides?

<https://www.mindat.org/>



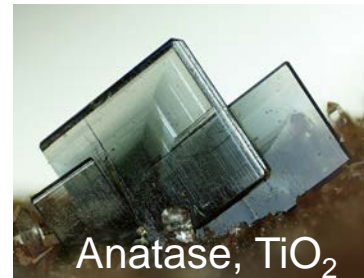
Hematite, Fe_2O_3



Rutile, TiO_2



Magnetite, Fe_3O_4



Anatase, TiO_2

Minerals: metal + oxygen;
defined composition and
crystal structure



Glass

<https://theglasspanty.com/>



Cabinet Mountains, MT



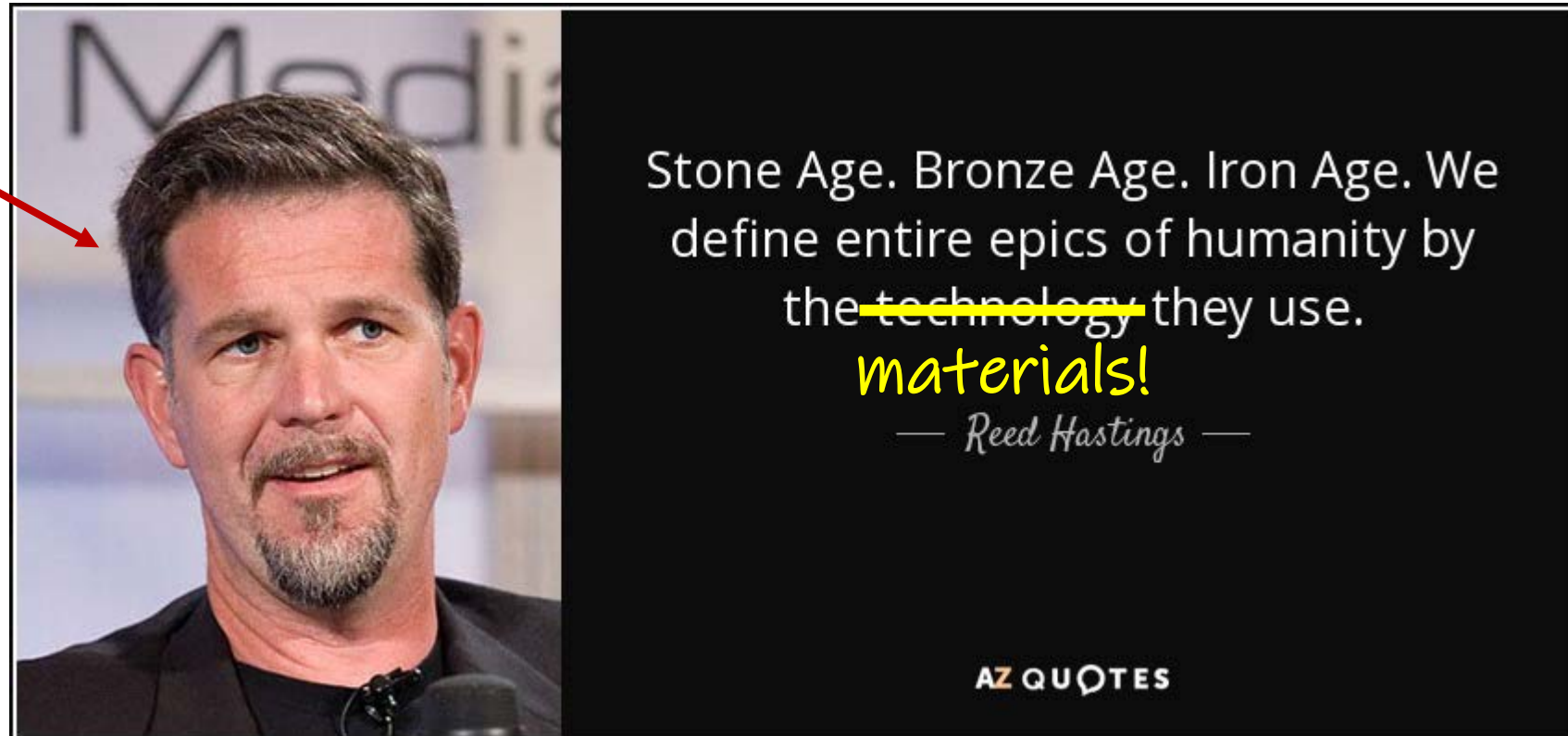
Rocks



Ceramics



NETFLIX
co-founder

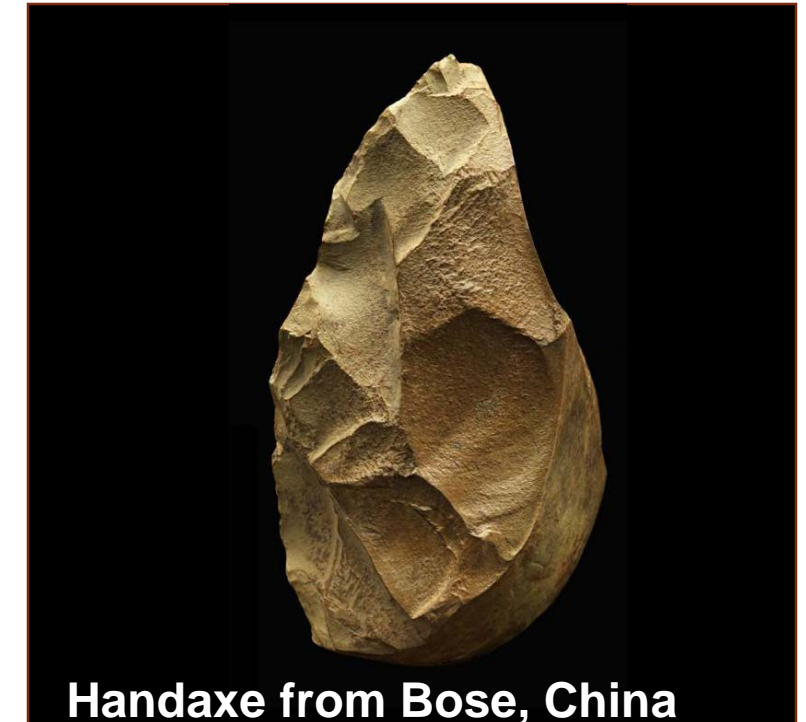
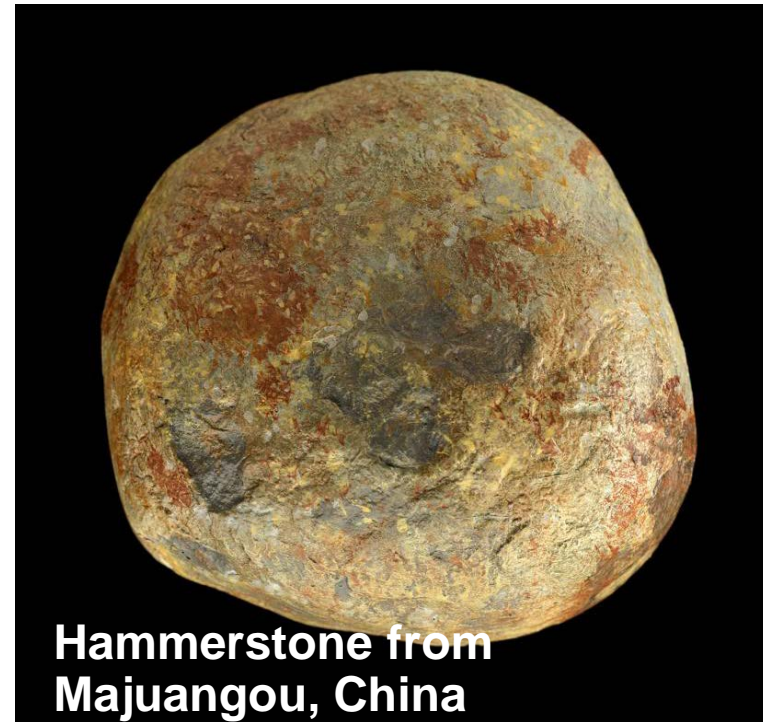


<https://www.azquotes.com/quote/918949>

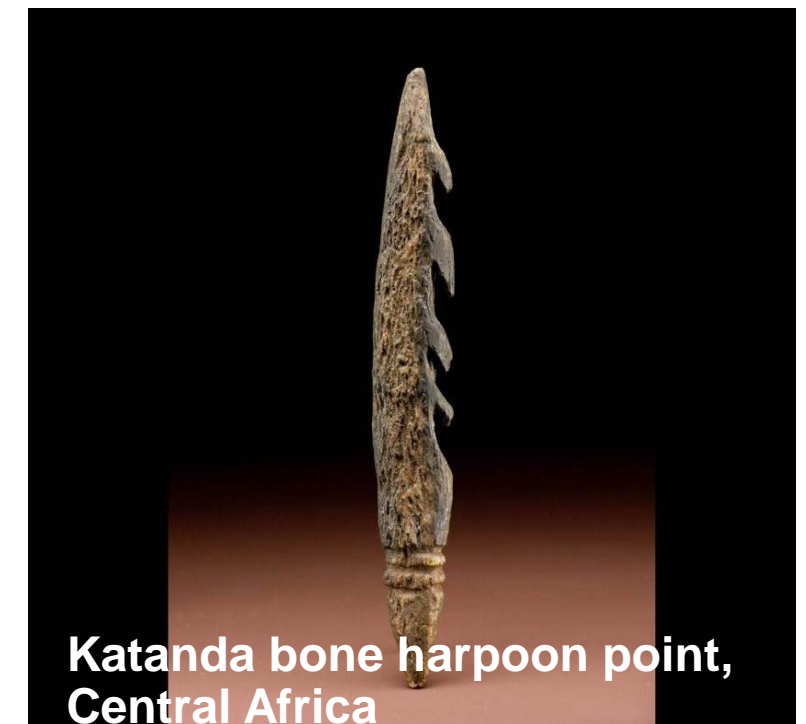
The (Original) Stone Age began 2.6 million years ago

- Which stone to use?
- Engineering advances required new materials
 - Bone, ivory, antler...

Early on...



Later...



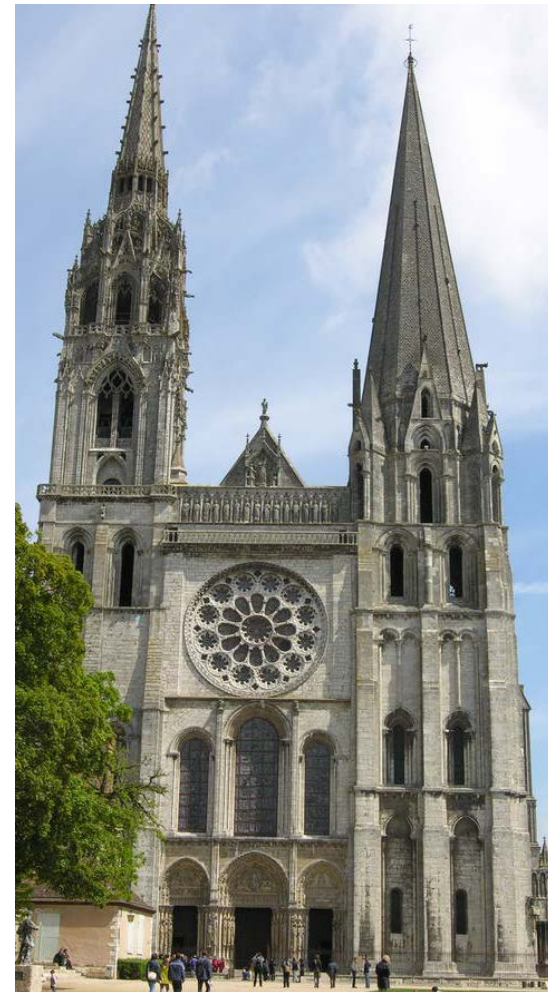
Stone through history: structural



Ancient Roman aqueduct, Segovia, Spain



Mesa Verde
National Park, CO



Chartres
Cathedral,
Chartres,
France



Independence Hall,
Philadelphia, PA



The Salk Institute, La Jolla, CA

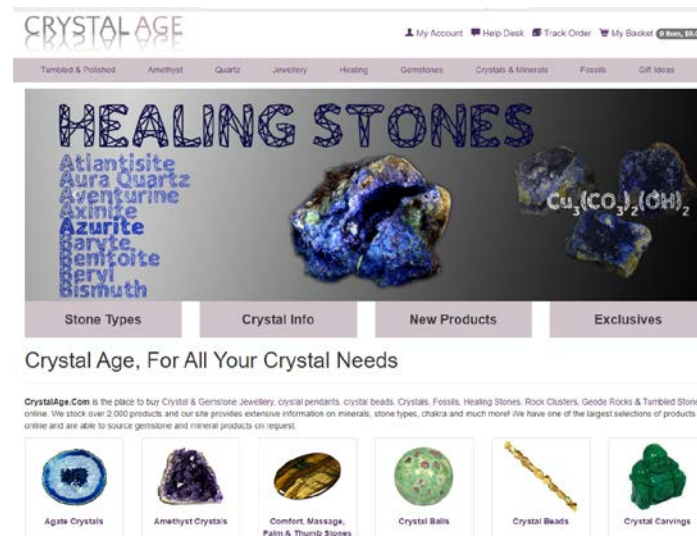
Stone through history: functional

Magnetism



Lodestone (magnetite)
compass, China, 220 BCE
https://www.smith.edu/hsc/museum/ancient_inventions/compass2.html

“Medicine”



Modern website selling crystals
for “healing”
<https://www.crystalage.com/>

Electrical insulation



Large ceramic insulators on
high voltage power lines
<https://www.quora.com/What-are-the-cones-on-power-lines>

Far fewer functional uses than structural...

Post-WW II: Materials *engineering* became materials *science*

Periodic Table of the Elements

1 H Hydrogen 1.008																	2 He Helium 4.003																														
3 Li Lithium 6.941	4 Be Beryllium 9.012																	5 B Boron 10.811	6 C Carbon 12.011	7 N Nitrogen 14.007	8 O Oxygen 15.999	9 F Fluorine 18.998	10 Ne Neon 20.180																								
11 Na Sodium 22.990	12 Mg Magnesium 24.305																	13 Al Aluminum 26.982	14 Si Silicon 28.086	15 P Phosphorus 30.974	16 S Sulfur 32.066	17 Cl Chlorine 35.453	18 Ar Argon 39.948																								
19 K Potassium 39.098	20 Ca Calcium 40.078	21 Sc Scandium 44.956	22 Ti Titanium 47.867	23 V Vanadium 50.942	24 Cr Chromium 51.996	25 Mn Manganese 54.938	26 Fe Iron 55.845	27 Co Cobalt 58.933	28 Ni Nickel 58.693	29 Cu Copper 63.546	30 Zn Zinc 65.38	31 Ga Gallium 69.723	32 Ge Germanium 72.631	33 As Arsenic 74.922	34 Se Selenium 78.972	35 Br Bromine 79.904	36 Kr Krypton 83.798																														
37 Rb Rubidium 85.468	38 Sr Strontium 87.62	39 Y Yttrium 88.906	40 Zr Zirconium 91.224	41 Nb Niobium 92.906	42 Mo Molybdenum 95.95	43 Tc Technetium 98.907	44 Ru Ruthenium 101.07	45 Rh Rhodium 102.906	46 Pd Palladium 106.42	47 Ag Silver 107.868	48 Cd Cadmium 112.411	49 In Indium 114.818	50 Sn Tin 118.710	51 Sb Antimony 121.760	52 Te Tellurium 127.6	53 I Iodine 126.904	54 Xe Xenon 131.294																														
55 Cs Cesium 132.905	56 Ba Barium 137.328	57-71	72 Hf Hafnium 178.49	73 Ta Tantalum 180.948	74 W Tungsten 183.84	75 Re Rhenium 186.207	76 Os Osmium 190.23	77 Ir Iridium 192.217	78 Pt Platinum 195.085	79 Au Gold 196.967	80 Hg Mercury 200.592	81 Tl Thallium 204.383	82 Pb Lead 207.2	83 Bi Bismuth 208.980	84 Po Polonium [208.982]	85 At Astatine 209.987	86 Rn Radon 222.018																														
87 Fr Francium 223.020	88 Ra Radium 226.025	89-103	104 Rf Rutherfordium [261]	105 Db Dubnium [262]	106 Sg Seaborgium [266]	107 Bh Bohrium [264]	108 Hs Hassium [269]	109 Mt Meitnerium [268]	110 Ds Darmstadtium [269]	111 Rg Roentgenium [272]	112 Cn Copernicium [277]	113 Nh Nihonium unknown	114 Fl Flerovium [289]	115 Mc Moscovium unknown	116 Lv Livermorium [293]	117 Ts Tennessine unknown	118 Og Oganesson unknown																														
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- Scientists learned to purify materials and put them together in new ways
- The periodic table of elements became a playground to invent new materials
- Materials science led to huge advances in both science and technology

The oxide Renaissance

Vacuum tubes



Vacuum tube diodes were invented in the early 1900's as a component of the first electronic circuits

- Bulky, delicate

Diode: allows electrical current to flow in one direction only

1926



J.E. Lillienfeld patents a solid-state field-effect transistor idea



High purity semiconductors

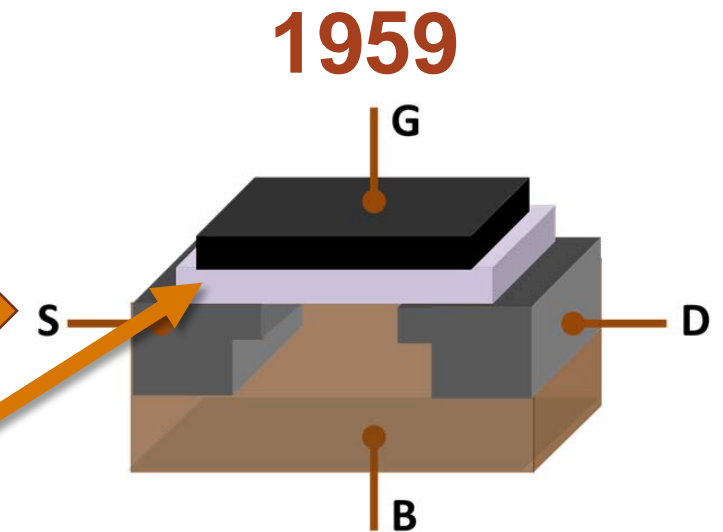
1947



Bell Labs invents first solid-state point-contact transistor



SiO₂ oxide layer on silicon semiconductor



Bell Labs invents first solid-state field-effect transistor

The oxide Renaissance

The experts look ahead

1965

Cramming more components onto integrated circuits

With unit cost falling as the number of components per circuit rises, by 1975 economics may dictate squeezing as many as 65,000 components on a single silicon chip

By Gordon E. Moore

Director, Research and Development Laboratories, Fairchild Semiconductor division of Fairchild Camera and Instrument Corp.

Moore's Law: transistors per chip will double every two years

The future of integrated electronics is the future of electronics itself. The advantages of integration will bring about a proliferation of electronics, pushing this science into many new areas.

Integrated circuits will lead to such wonders as home computers—or at least terminals connected to a central computer—automatic controls for automobiles, and personal portable communications equipment. The electronic wristwatch needs only a display to be feasible today.

But the biggest potential lies in the production of large systems. In telephone communications, integrated circuits in digital filters will separate channels on multiplex equipment. Integrated circuits will also switch telephone circuits and perform data processing.

Computers will be more powerful, and will be organized in completely different ways. For example, memories built of integrated electronics may be distributed throughout the

machine instead of being concentrated in a central unit. In addition, the improved reliability made possible by integrated circuits will allow the construction of larger processing units. Machines similar to those in existence today will be built at lower costs and with faster turn-around.

Present and future

By integrated electronics, I mean all the various technologies which are referred to as microelectronics today as well as any additional ones that result in electronics functions supplied to the user as irreducible units. These technologies were first investigated in the late 1950's. The object was to miniaturize electronics equipment to include increasingly complex electronic functions in limited space with minimum weight. Several approaches evolved, including microassembly techniques for individual components, thin-film structures and semiconductor integrated circuits.

Each approach evolved rapidly and converged so that each borrowed techniques from another. Many researchers believe the way of the future to be a combination of the various approaches.

The advocates of semiconductor integrated circuitry are already using the improved characteristics of thin-film resistors by applying such films directly to an active semiconductor substrate. Those advocating a technology based upon films are developing sophisticated techniques for the attachment of active semiconductor devices to the passive film arrays.

Both approaches have worked well and are being used in equipment today.

The author

Dr. Gordon E. Moore is one of the new breed of electronic engineers, schooled in the physical sciences rather than in electronics. He earned a B.S. degree in chemistry from the University of California and a Ph.D. degree in physical chemistry from the California Institute of Technology. He was one of the founders of Fairchild Semiconductor and has been director of the research and development laboratories since 1959.

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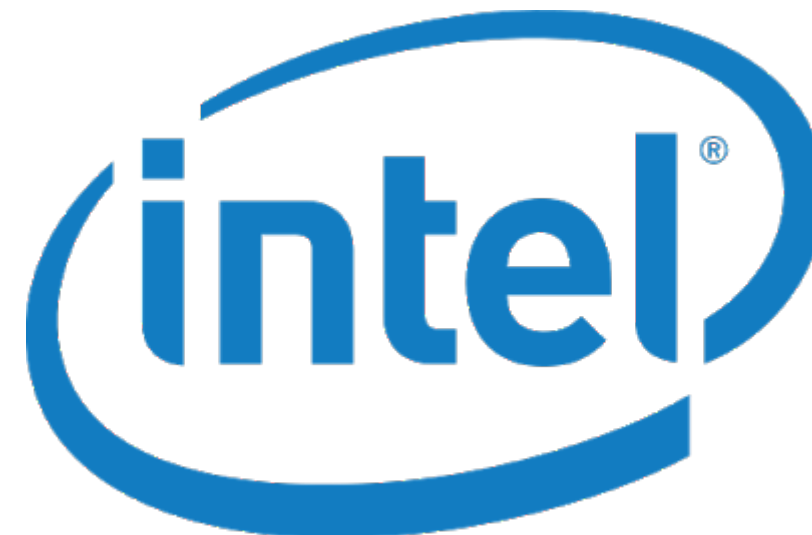
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Gordon Moore:
Ph.D. degree in physical chemistry

Robert Noyce:
Ph.D. degree in physics

1968:
Moore and Noyce co-founded Intel Corp.



The oxide Renaissance

The experts look ahead

1965

Cramming more components

Gordon Moore:

Ph.D. degree in physical chemistry

Chemistry + physics = materials science!

Computer technology advances by understanding
and controlling the *materials* of the chip(s)

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The oxide Renaissance

Everything Gordon Moore foresaw for “integrated electronics” has come to pass!

<https://www.popularmechanics.com/cars/how-to/a7386/how-it-works-the-computer-inside-your-car/>



Walmart CYBER MONDAY 2019

Cyber Monday Deals Start Monday December 2nd at 12AM ET

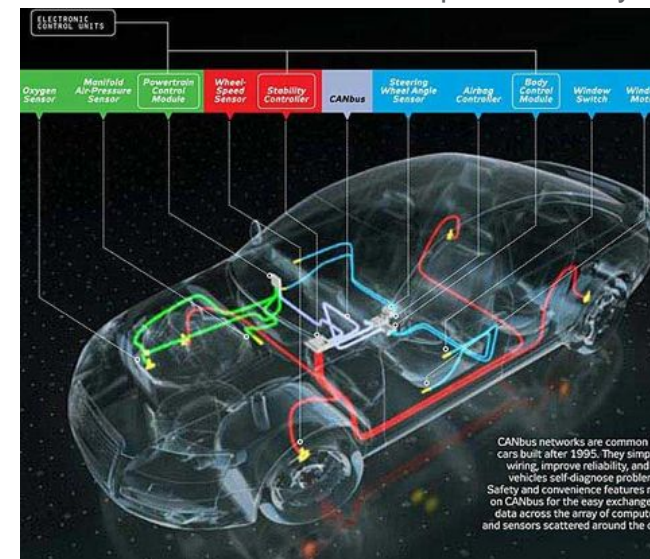
Shop Now! >

Lenovo 15.6 R5 laptop
\$499 ~~\$299.00~~

VIZIO 55" Class 4K Ultra HD HDR Smart LED TV
\$478.00 ~~\$279.99~~

\$450.00 Gift Card with Purchase and Activation of a Samsung Galaxy S10 Phone

These deals are going fast! Pricing and availability subject to change. MADE WITH FROM THE DEAL EXPERTS AT BlackFriday.com



<https://www.tesla.com/autopilot>



The oxide Renaissance

Smartphones use **at least 70** of the 83 non-radioactive elements!



ELEMENTS OF A SMARTPHONE

ELEMENTS COLOUR KEY: ● ALKALI METAL ● ALKALINE EARTH METAL ● TRANSITION METAL ● GROUP 13 ● GROUP 14 ● GROUP 15 ● GROUP 16 ● HALOGEN ● LANTHANIDE

SCREEN

Indium tin oxide is a mixture of indium oxide and tin oxide, used in a transparent film in the screen that conducts electricity. This allows the screen to function as a touch screen.

The glass used on the majority of smartphones is an aluminosilicate glass, composed of a mix of alumina (Al_2O_3) and silica (SiO_2). This glass also contains potassium ions, which help to strengthen it.

A variety of Rare Earth Element compounds are used in small quantities to produce the colours in the smartphone's screen. Some compounds are also used to reduce UV light penetration into the phone.

49 In Indium	8 O Oxygen	
50 Sn Tin		
13 Al Aluminium	14 Si Silicon	
8 O Oxygen	19 K Potassium	
39 Y Yttrium	57 La Lanthanum	65 Tb Terbium
59 Pr Praseodymium	63 Eu Europium	66 Dy Dysprosium
64 Gd Gadolinium		

ELECTRONICS

Copper is used for wiring in the phone, whilst copper, gold and silver are the major metals from which microelectrical components are fashioned. Tantalum is the major component of micro-capacitors.

Nickel is used in the microphone as well as for other electrical connections. Alloys including the elements praseodymium, gadolinium and neodymium are used in the magnets in the speaker and microphone. Neodymium, terbium and dysprosium are used in the vibration unit.

Pure silicon is used to manufacture the chip in the phone. It is oxidised to produce non-conducting regions, then other elements are added in order to allow the chip to conduct electricity.

Tin & lead are used to solder electronics in the phone. Newer lead-free solders use a mix of tin, copper and silver.

29 Cu Copper	47 Ag Silver	
79 Au Gold	73 Ta Tantalum	
28 Ni Nickel	66 Dy Dysprosium	59 Pr Praseodymium
65 Tb Terbium	60 Nd Neodymium	64 Gd Gadolinium
14 Si Silicon	8 O Oxygen	51 Sb Antimony
33 As Arsenic	15 P Phosphorus	31 Ga Gallium
50 Sn Tin	82 Pb Lead	

BATTERY

The majority of phones use lithium ion batteries, which are composed of lithium cobalt oxide as a positive electrode and graphite (carbon) as the negative electrode. Some batteries use other metals, such as manganese, in place of cobalt. The battery's casing is made of aluminium.

3 Li Lithium	27 Co Cobalt	8 O Oxygen
6 C Carbon	13 Al Aluminium	

CASING

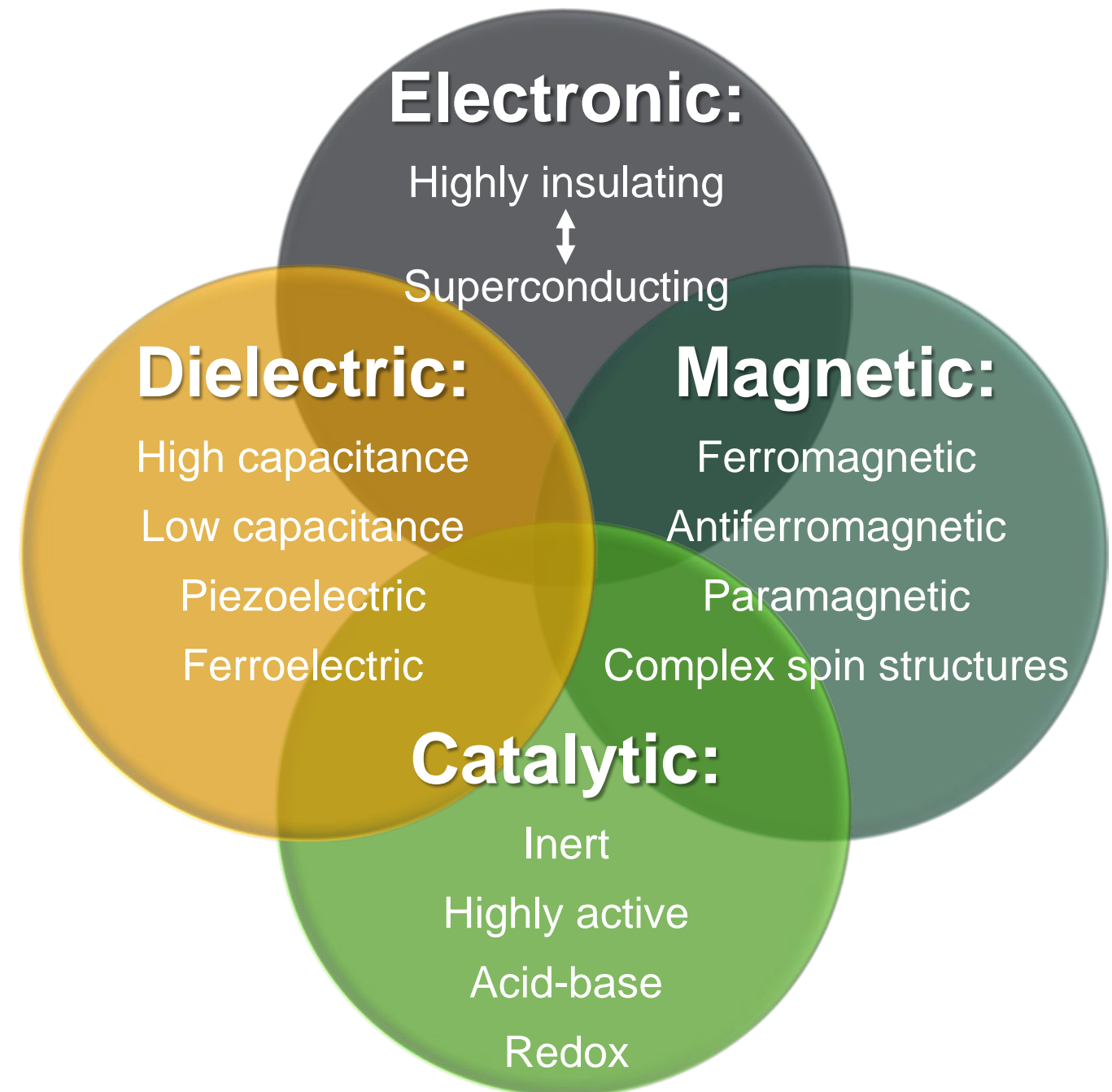
Magnesium compounds are alloyed to make some phone cases, whilst many are made of plastics. Plastics will also include flame retardant compounds, some of which contain bromine, whilst nickel can be included to reduce electromagnetic interference.

6 C Carbon	12 Mg Magnesium
35 Br Bromine	28 Ni Nickel

Modern functional oxides

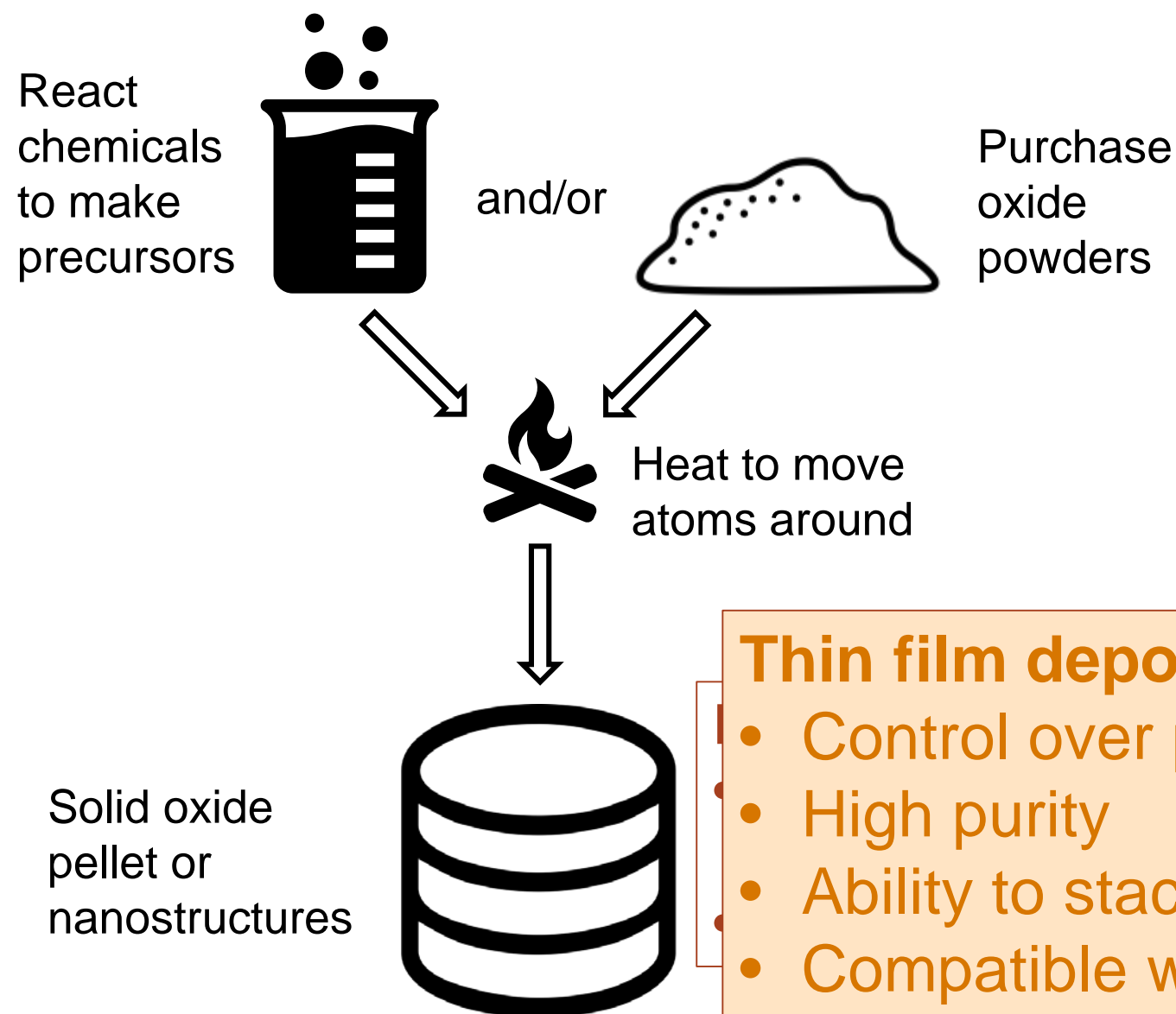
What we have learned in
the last ~70 years:

**Oxides have the
widest range of
“functional properties”
of any class of
materials**



How do we make oxides to study?

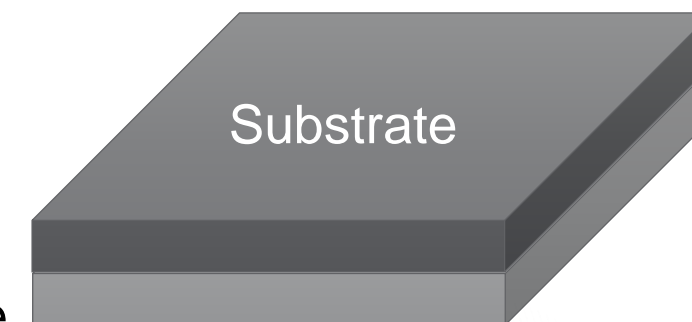
A better way:



Thin film deposition:

- Control over phase
- High purity
- Ability to stack oxides
- Compatible with microelectronics

"Grow" oxide film on substrate



Evaporation

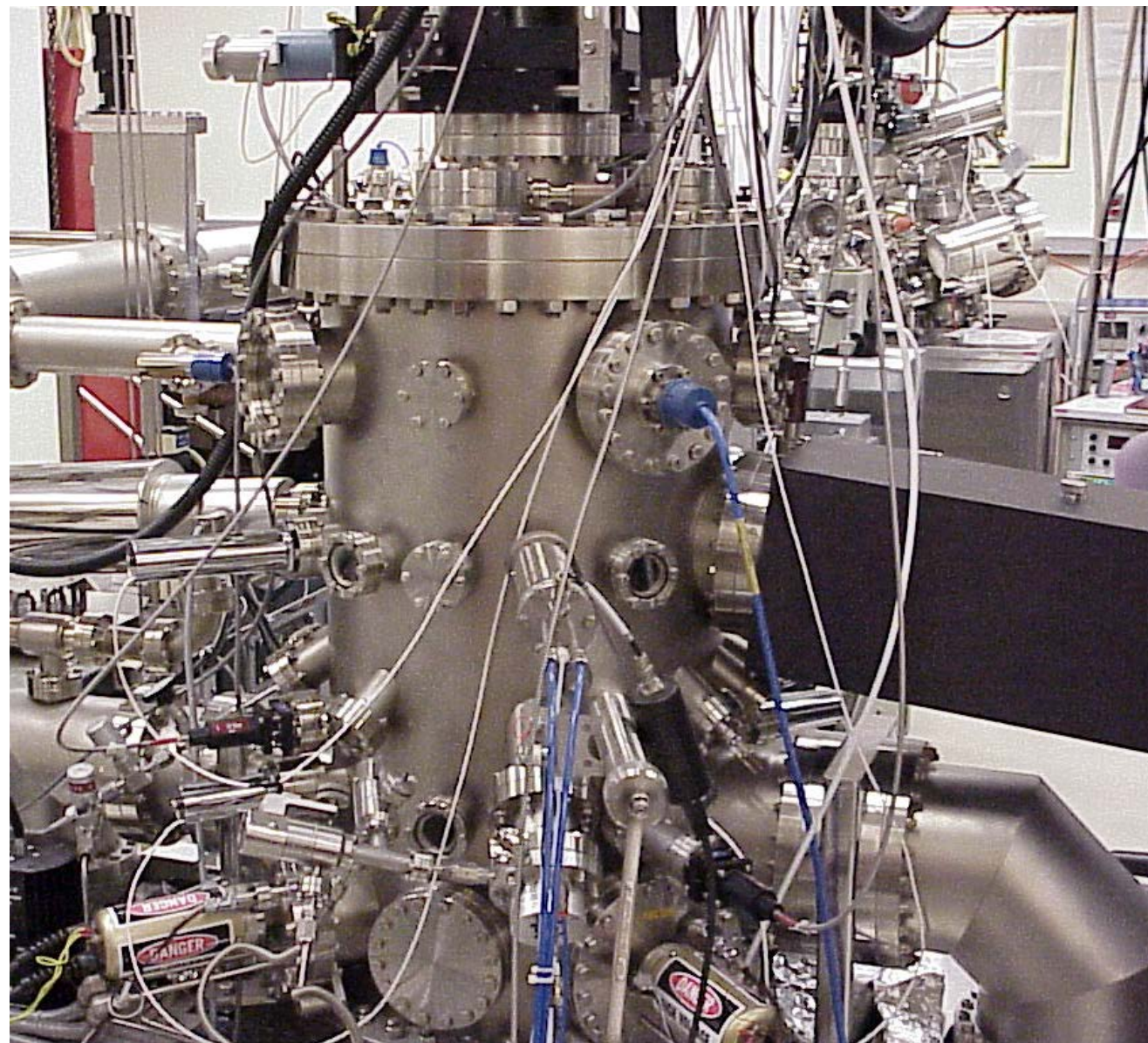
Purchase high purity metals



Heat to very high temperatures



Molecular beam epitaxy



Ultrahigh vacuum chamber for MBE

High purity oxides

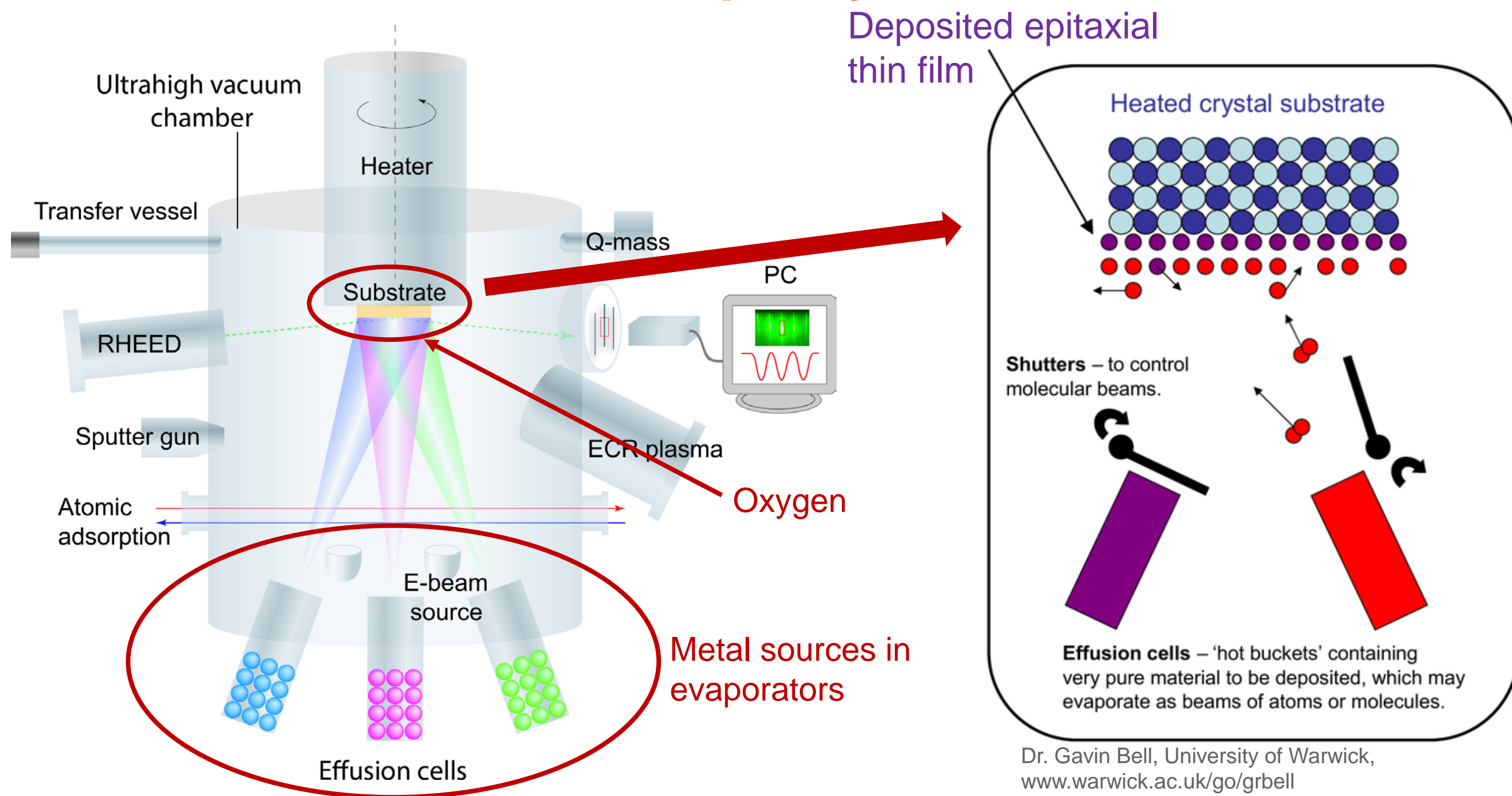
Ultraclean
environment

“Ultrahigh vacuum”
chamber

~15 pounds (~ 2
gallon jugs of milk)
pressing on every
square inch!



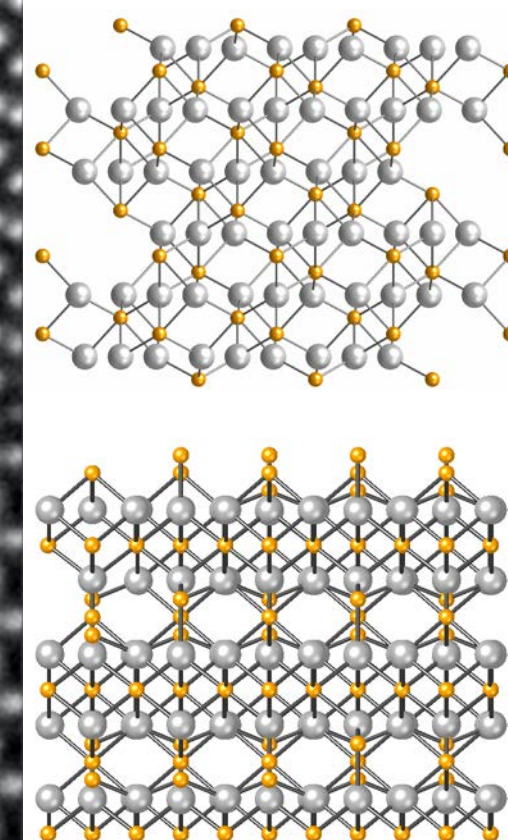
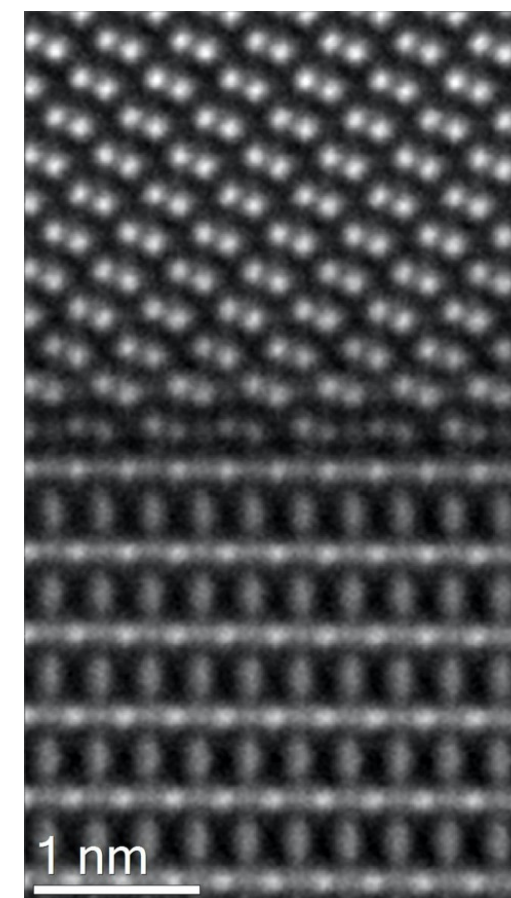
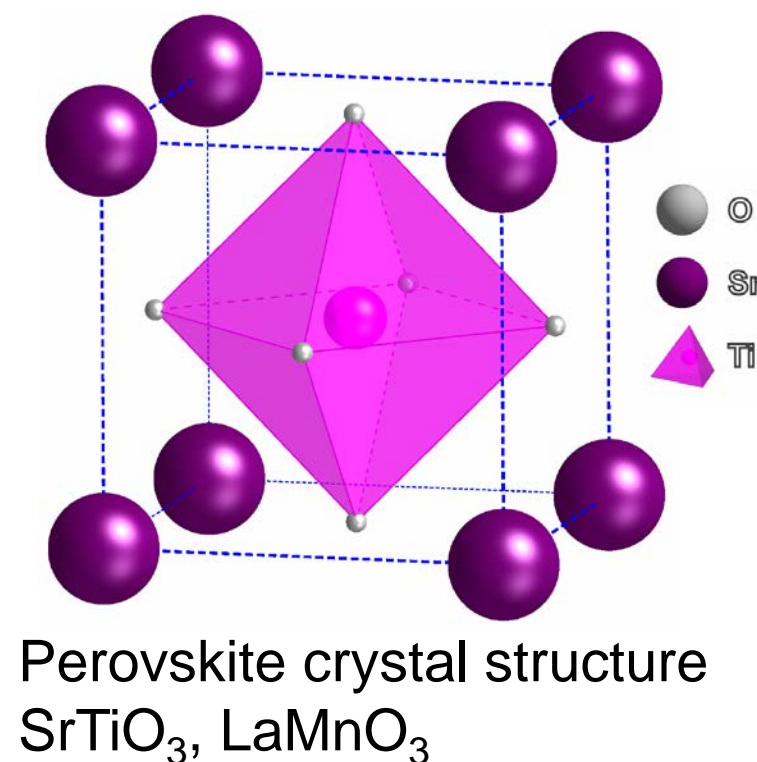
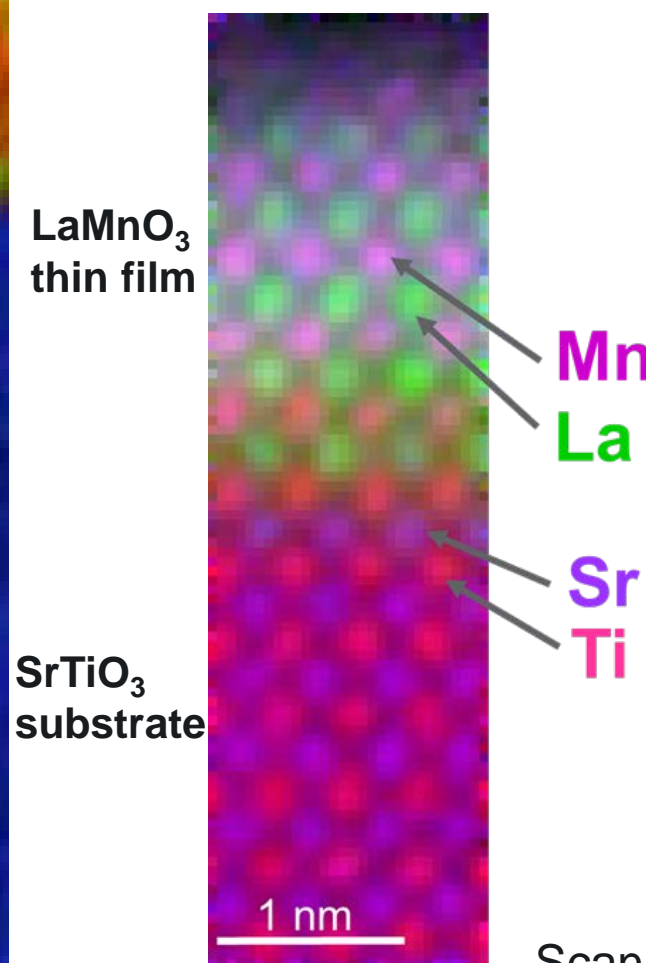
Molecular beam epitaxy



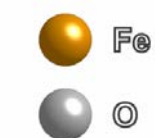
Atomically precise deposition

Epitaxy:

The natural or artificial growth of crystals on a crystalline substrate that controls the structure of the thin film.



Hematite,
Fe₂O₃

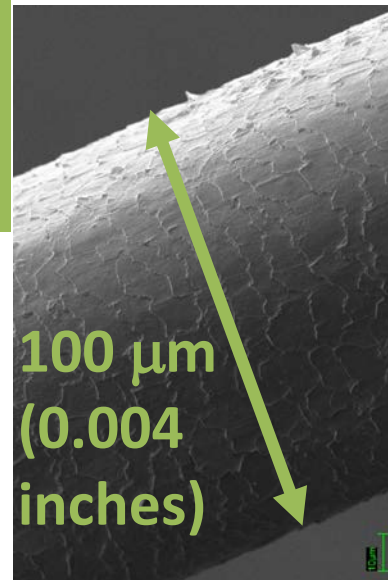


Magnetite,
Fe₃O₄

Scanning transmission electron microscopy (STEM) images

How thin is a “thin” film?

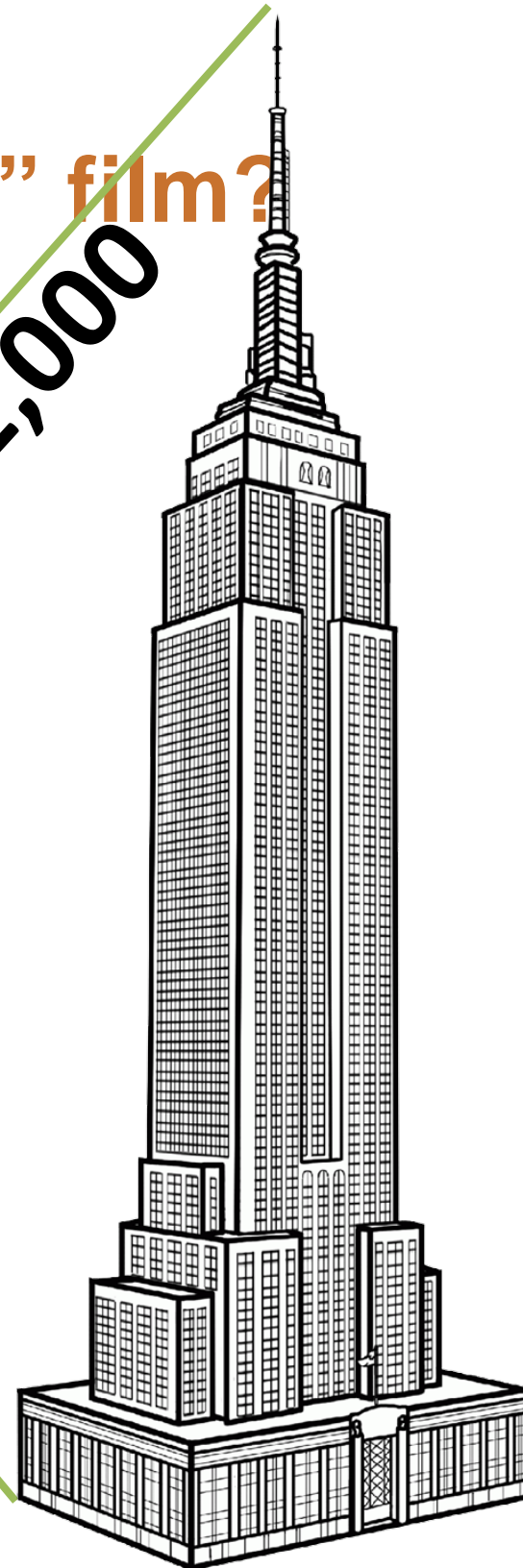
Thin films are
~10,000 times
thinner than a
human hair



Hair

100 μm
(0.004
inches)

x 4,362,000



Empire State Building: 102 stories, 1,454 ft tall

**Thin film:
10 nm thick
(0.01 μm)**



1 $\frac{3}{4}$ inches

Modern functional oxides

Applications of functional oxides:

Microelectronics – spintronics, photonics

Data storage – RAM

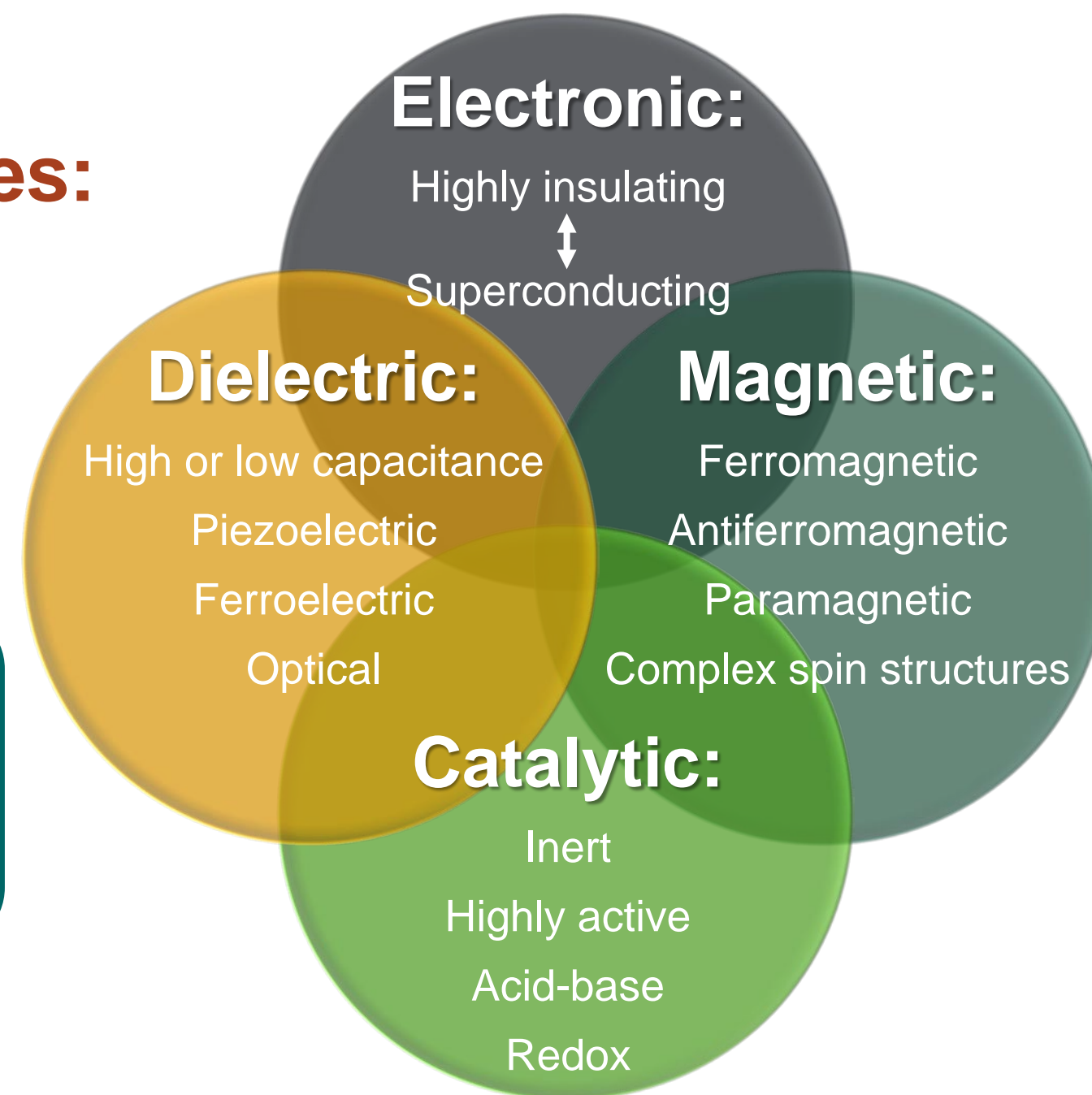
Quantum computing

Sensors – gas, chemicals

Energy generation – solar cells, fuel cells

Energy storage – ion batteries

Chemical catalysis – green chemistry



Intertwined energy and climate crisis

- **Goal: reduce or eliminate our dependence on fossil fuels**

- Fossil fuels are a limited resource
- Burning fossil fuels releases CO₂, causing climate change
- Global supply chain is a national security risk

- **Solar energy is free!**

- Harvesting it is not free – or easy – but can be very environmentally friendly
- Generating energy near the use point leads to regional and national energy security

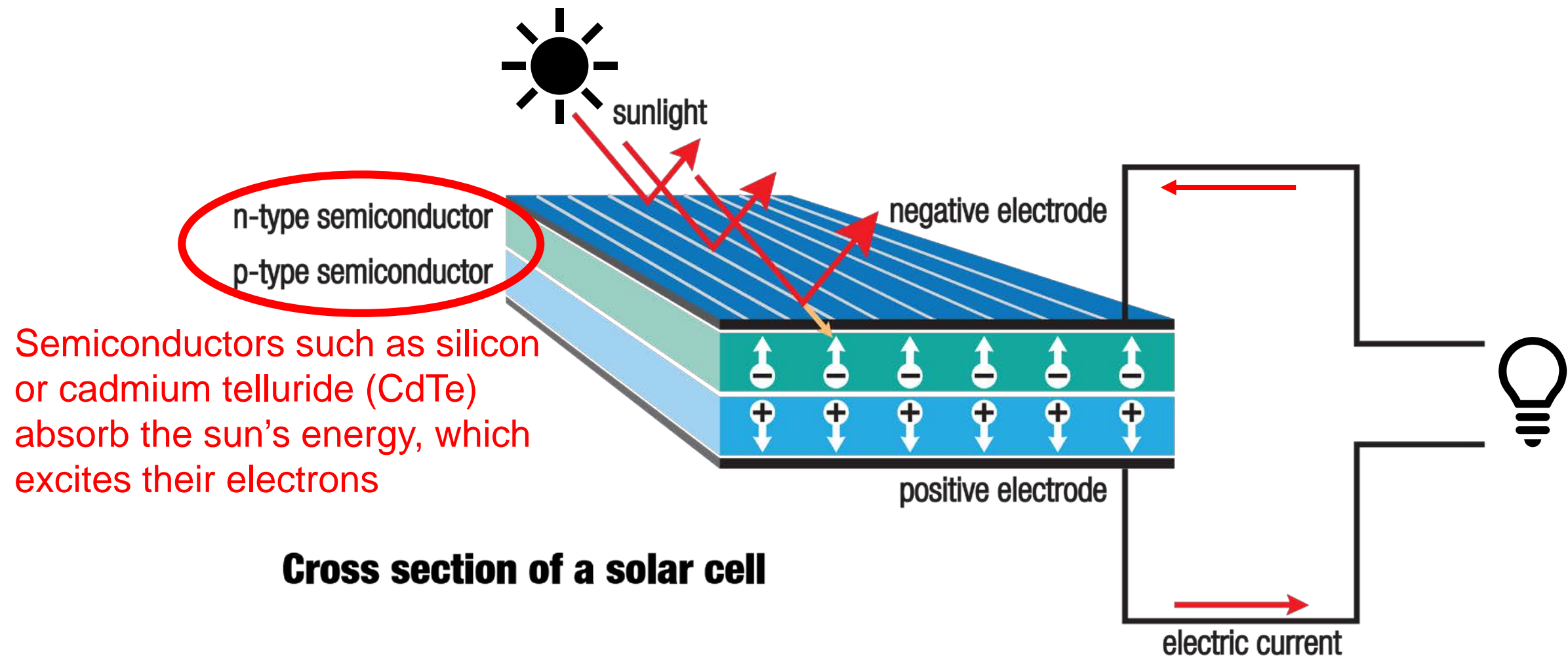


(Bret Hartman/Reuters)



<https://www.flickr.com/photos/minagri/39828094670/>

How do solar cells work?



<https://www.visualcapitalist.com/animation-how-solar-panels-work/>

Areas for improvement:

Higher efficiency (more electricity)

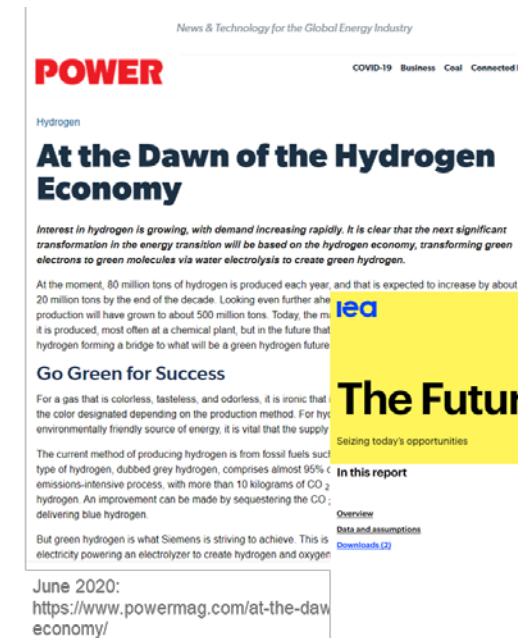
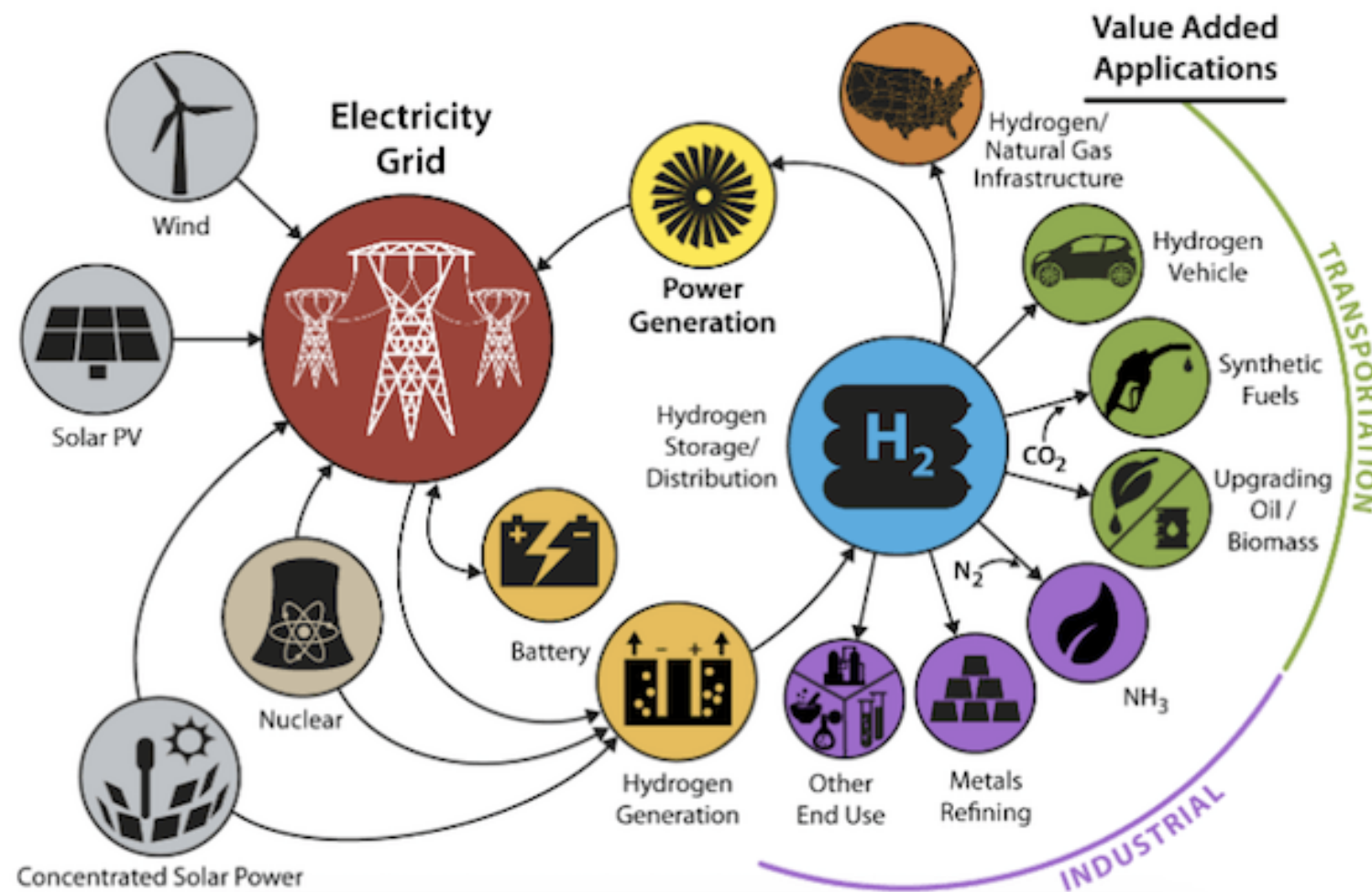
Cheaper materials

Energy storage because sunlight is intermittent

Alternative approach

Store solar energy as a **fuel** — Energy carrier
— Portable
— Used on demand

Hydrogen (H₂) is a promising fuel with a high energy density



The Future of Hydrogen

Seizing today's opportunities

In this report
Overview
Data and assumptions
Download (2)

June 2020:
<https://www.powermag.com/at-the-dawn-of-the-hydrogen-economy/>

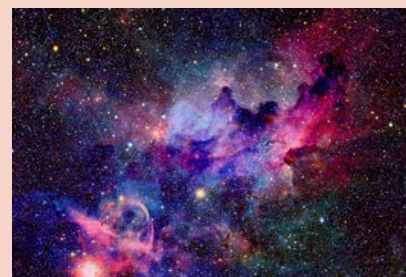
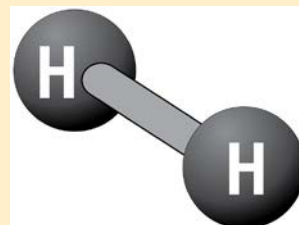
"Hydrogen is today enjoying unprecedented momentum. The world should not miss this unique chance to make hydrogen an important part of our clean and secure energy future."

June 2019:
<https://www.iea.org/reports/the-future-of-hydrogen>



Getting to know hydrogen

The H-H chemical bond in H_2 stores a lot of energy, making H_2 an energy-dense fuel



Hydrogen is literally all around us - it makes up 75% of the elemental mass of the *universe*! – but H_2 in Earth's atmosphere is only 1 part per million (ppm)



Most hydrogen on Earth is chemically bonded with other elements to make water (H_2O) and organic compounds

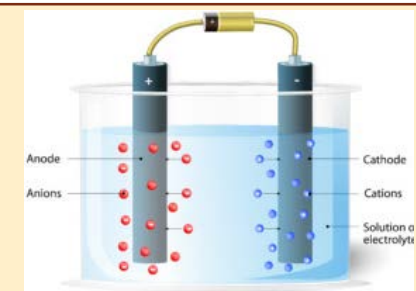


Manufacture
of H_2 :

Steam
reforming of
methane (CH_4)



Electrolysis
of water

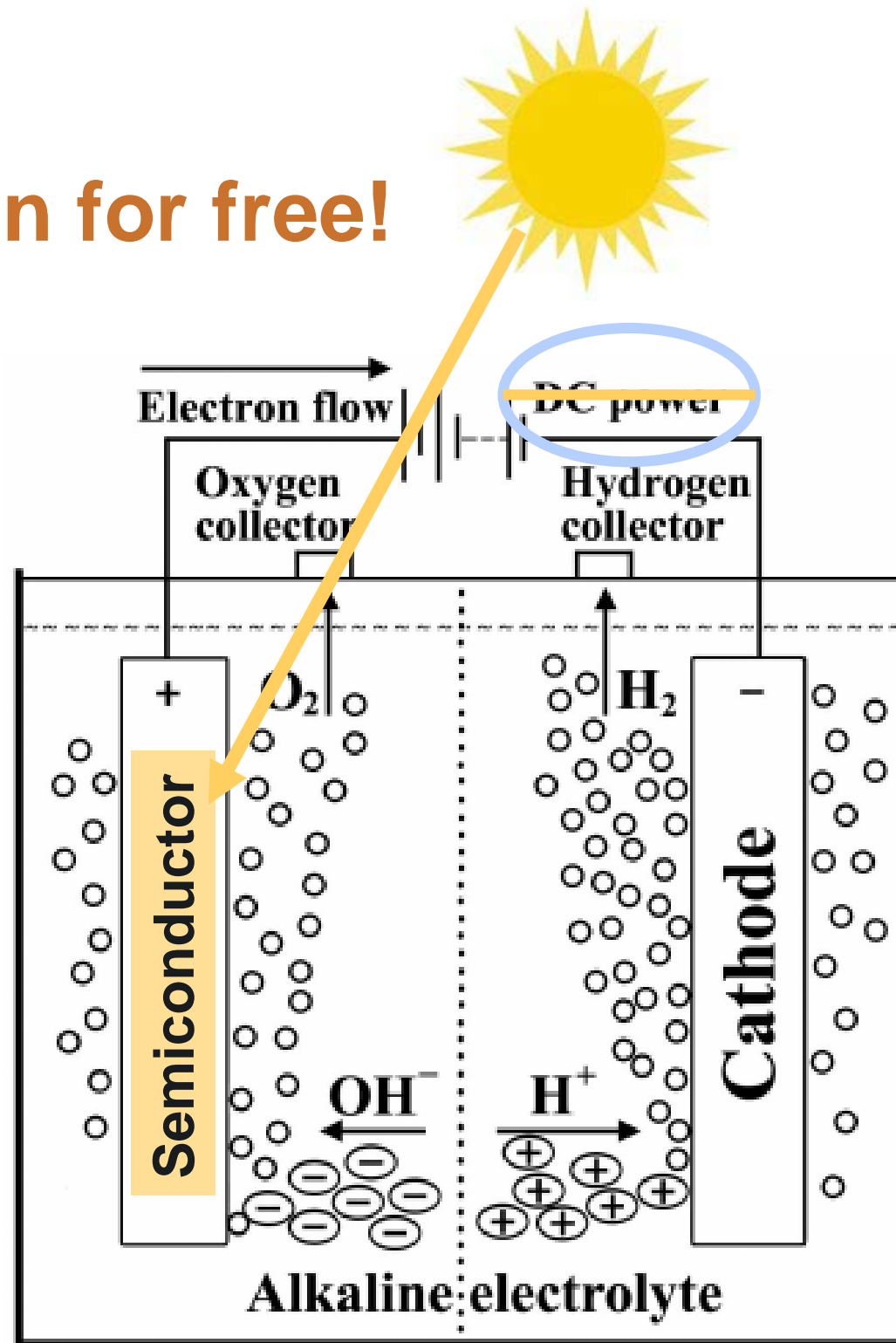


What if we could get H_2 for (almost) free with no environmental impact?

Hydrogen for free!

Electrolysis of H₂O:

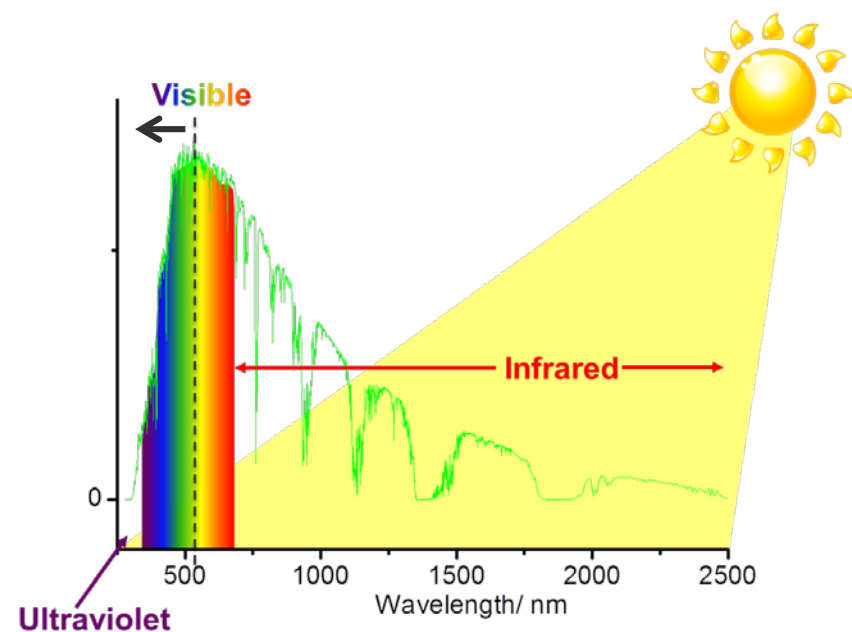
- Anode and cathode (electrodes) placed in water
- Apply energy in form of voltage across electrodes
- H₂O splits and forms O₂ at anode, H₂ at cathode
- Energy-loss process: more energy is supplied (voltage) than obtained in H₂ bonds



Improvement: Solar water splitting (Photoelectrolysis)

- Replace anode with semiconductor
- Replace applied voltage with sunlight
- Semiconductor anode absorbs sunlight, generating electrons and holes that react to split H₂O
- Energy-efficient process!

What are the properties of a good photocatalyst?



**Narrow bandgap to
absorb most of the
solar spectrum
Ideal: ~ 1.5 eV**

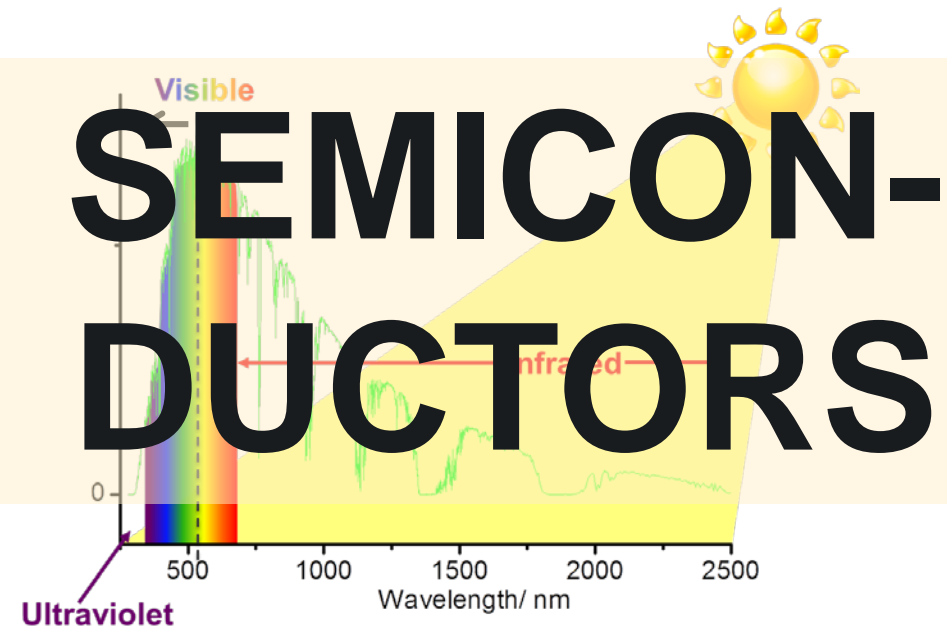


**Stable in
aqueous (water)
environments**

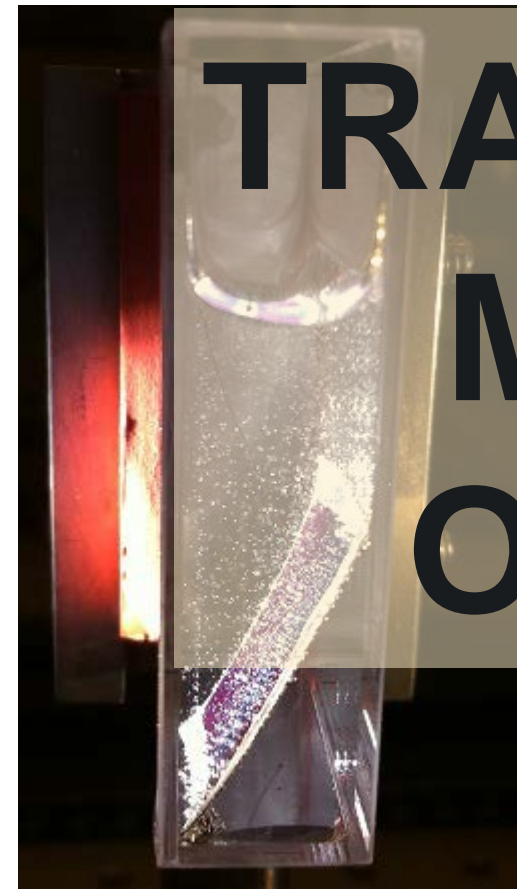


**Earth-abundant
elements for
economical scalability
Preferably non-toxic**

What are the properties of a good photocatalyst?



**Narrow bandgap to
absorb most of the
solar spectrum
Ideal: ~1.5 eV**



**Stable in
aqueous (water)
environments**

**TRANSITION
METAL
OXIDES**

**Earth-abundant
elements for
economical scalability
Preferably non-toxic**



Let's use rust!

Hematite (Fe_2O_3) is an appealing photocatalyst:

Narrow bandgap (2.1 eV) to absorb much of the solar spectrum

Stable in aqueous environments

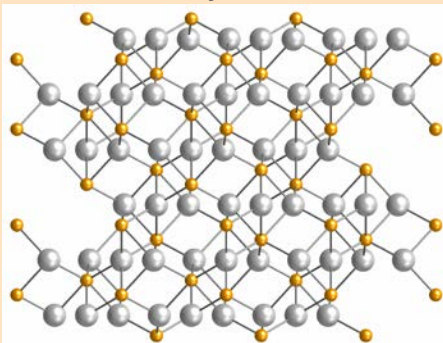
Non-toxic: important in biology

Earth abundance: 4th most abundant element in the crust



Tuning the properties of hematite thin films

Hematite crystal structure



Drawbacks to hematite (Fe_2O_3) for solar water splitting:

Too electrically insulating

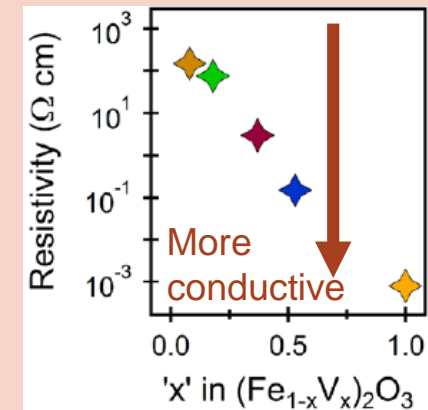
Does not adsorb all of the solar spectrum

Does not efficiently turn sunlight into electrons

Improve the electrical conductivity of hematite:

Replace some Fe ions with Ti or V
Ti or V donates one extra electron to the material

These extra electrons increase the electrical conductivity

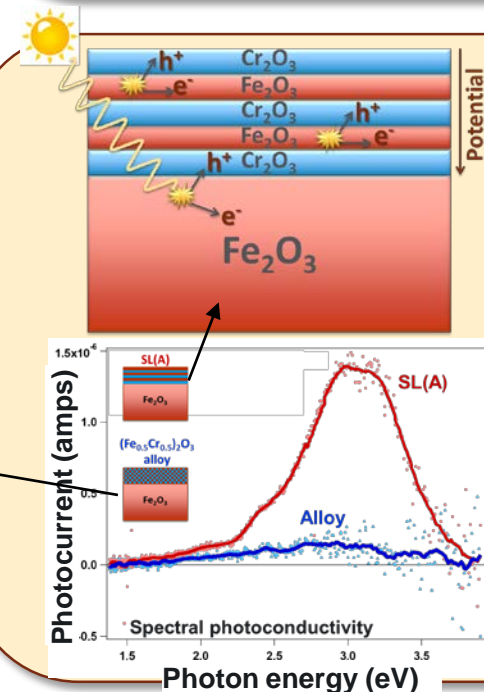
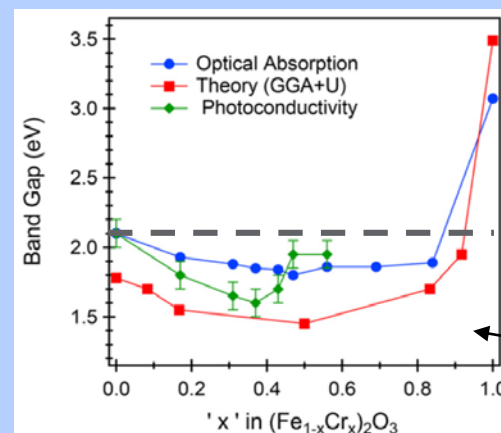


Improve the range of sunlight absorption:

Replace some Fe ions with Cr

Addition of Cr ions narrows the bandgap below Fe_2O_3 or Cr_2O_3

Narrower bandgap can absorb more of the solar spectrum



Improve the sunlight-to-electrons efficiency

Need to separate negative electrons from positive holes

Separate with voltage

Grow $\text{Fe}_2\text{O}_3/\text{Cr}_2\text{O}_3$ layers with a built-in voltage (potential)

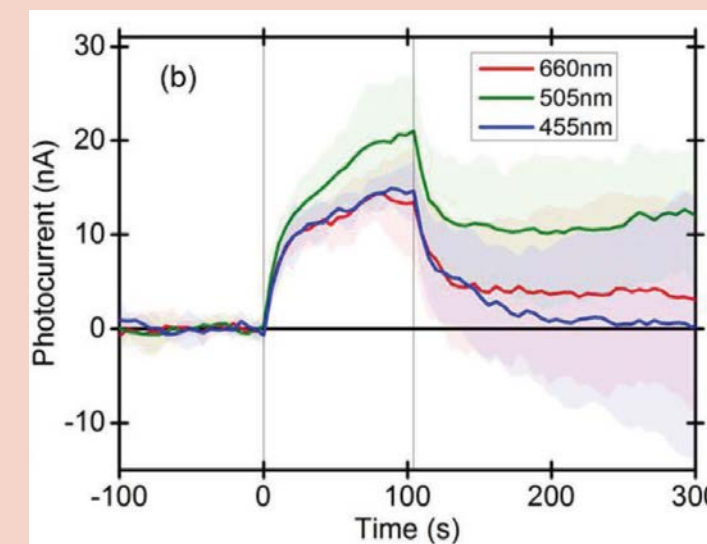
Beyond Fe_2O_3 and summary

Beyond Fe_2O_3 : Fe_2CrO_4

Based on magnetite (Fe_3O_4) lattice
Magnetite has high (metallic) conductivity
Introducing Cr lowers the conductivity;
 Fe_2CrO_4 is semiconducting
Improved efficiency to turn sunlight into
electrons

Electrical conductivity:

Fe_3O_4 : metallic
↓
 Fe_2CrO_4 : semiconducting
↓
 FeCr_2O_4 : insulating



Summary of water splitting with iron oxides

We have engineered the properties of Fe_2O_3 by doping with Ti, V, Cr
Gained fundamental insight into the effect of these dopants on Fe_2O_3

Explored the semiconducting spinel Fe_2CrO_4

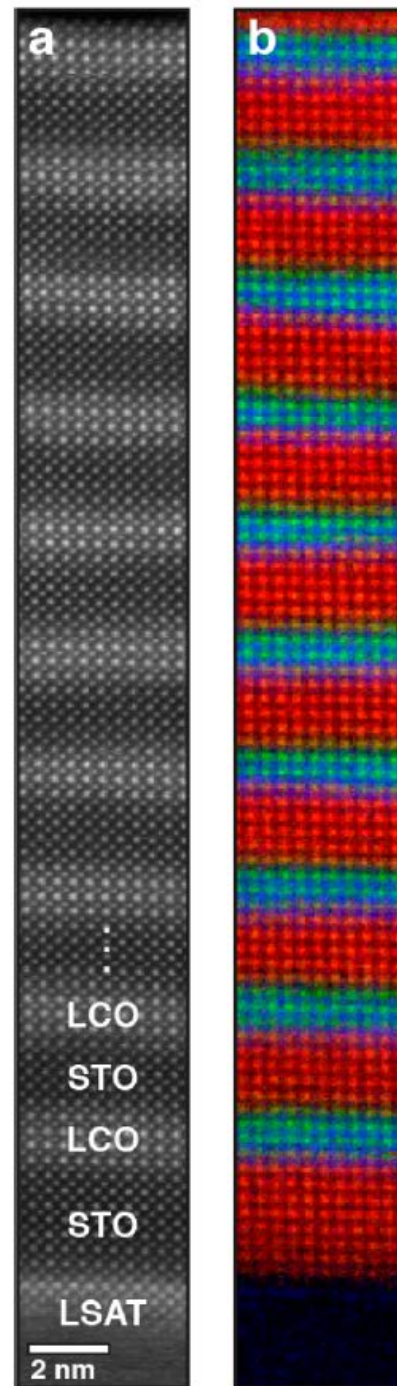
These fundamental studies are the goal of our research

Others are using these results in applications of iron oxides

Outlook for functional oxides

- Modern technology is built on materials science – understanding the chemistry and physics of materials
- The underlying principles that result in the wide range of properties of oxides are beginning to be understood systematically
 - Epitaxial thin films are key to these systematic studies
- The next frontier: emergent properties at interfaces between oxides

<http://images.lipy.com/bang>



We value your feedback!

<https://www.surveymonkey.com/r/PNNL090820>

Join us for our next webinar



**Solving the World's Biggest
Problems on the Smallest Scale**

Presented by: Heather Olson

Tuesday, October 13, 2020

7:00 pm

ZOOM



THANK YOU!



Tiffany Kaspar
Materials Scientist

Phone: (509) 371-6503
tiffany.kaspar@pnnl.gov

902 Battelle Boulevard
P.O. Box 999, MSIN K8-88
Richland, WA 99352

www.pnnl.gov



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